

ABSTRACT OF THE DISCLOSURE

The present invention has the feature that, in  
a semiconductor laser apparatus having a negative  
electrode and a positive electrode sandwiching an  
5 active region (active region layer), and an optical  
resonance chamber which is defined by a high-reflecting  
mirror and an output mirror positioned at the both  
end portions thereof, the positive electrode and  
an oscillation optical axis which is the axis of  
10 the optical resonance chamber are made so as to be  
non-parallel.